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April 2017

# FPF3042 IntelliMAX<sup>™</sup> 18 V-Rated, Dual-Input, Single-Output, Power-Source-Selector Switch

# Features

- Dual-Input, Single-Output Load Switch (DISO)
- Input Supply Operating Range:
  - 4.0 V~12.4 V at  $V_{\text{IN}}$
  - 4.0 V~12.4 V at V<sub>BUS</sub>
- Typical R<sub>ON</sub>:
  - = 95 m $\Omega$  at V<sub>IN</sub>=5 V
  - 70 mΩ at V<sub>BUS</sub>=5 V
- Bidirectional Switch for VIN and VBUS
- Slew Rate Controlled:
  - 50  $\mu$ s at V<sub>IN</sub> for < 4.7  $\mu$ F C<sub>OUT</sub>
  - 90 μs at V<sub>BUS</sub> for < 4.7 μF C<sub>OUT</sub>
- Maximum I<sub>SW</sub>: 2.7 A per Channel
- Break-Before-Make Transition
- Under-Voltage Lockout (UVLO)
- Over-Voltage Lockout (OVLO)
- Thermal Shutdown
- Logic CMOS IO Meets JESD76 Standard for GPIO Interface and Related Power Supply Requirements
- ESD Protected:
  - Human Body Model: >3 kV
  - Charged Device Model: >1.5 kV
  - IEC 61000-4-2 Air Discharge: >15 kV
  - IEC61000-4-2 Contact Discharge: >8 kV

## Description

The FPF3042 is an 18 V-rated Dual-Input Single-Output (DISO) load switch consisting of two channels of slewrate-controlled, low-on-resistance, N-channel MOSFET switches with protection features. The slew-ratecontrolled turn-on characteristic prevents inrush current and the resulting excessive voltage droop on the input power rails. The input voltage range operates from 4.0 V to 12.4 V at both V<sub>BUS</sub> and V<sub>IN</sub> to align with the needs of high-voltage portable device power rails.

Both  $V_{\text{IN}}$  and  $V_{\text{BUS}}$  have the over-voltage protection of 14 V (typical) to avoid damage to the system.

 $V_{\text{IN}}$  and  $V_{\text{BUS}}$  bidirectional switching allows reverse current from  $V_{\text{OUT}}$  to  $V_{\text{IN}}$  or  $V_{\text{BUS}}$  for On-The-Go, (OTG) Mode. The switching is controlled by logic input EN and  $V_{\text{IN}\_\text{SEL}}$  is capable of interfacing directly with low-voltage control signal General-Purpose Input / Output (GPIO).

FPF3042 is available in 1.76 mm x 1.96 mm Wafer-Level Chip-Scale Package (WLCSP), 16-bump, 0.4 mm pitch.

# Applications

- Input Power-Selection Block Supporting USB and Wireless Charging
- Smart Phone / Tablet PC

Ordering in					
Part Number	Top Mark	Channel	Typical R <sub>oN</sub> per Channel at 5 V <sub>IN</sub>	Rise Time (t <sub>R</sub> )	Package
			95 m $\Omega$ for $V_{\text{IN}}$	50 $\mu s$ for $V_{\text{IN}}$	16-Bump, 1.76 mm x 1.96 mm,
FPF3042UCX	TR	DISO	70 m $\Omega$ for V <sub>BUS</sub>	90 µs for V <sub>BUS</sub>	Wafer-Level Chip-Scale Package (WLCSP), 0.4 mm Pitch

# **Ordering Information**





**Pin Configuration** 



<u>Top View</u> Figure 4. Pin Assignment (Top View)

### **Pin Description**



Figure 5. Pin Assignment (Bottom View)

Pin #	Name	Input / Output	Description
A1, B1, C1	VBUS	Input / Output	$V_{BUS}$ at USB: Power input / output; bi-directional switch when $V_{IN\_SEL} = LOW$ .
A4, B4, C4	Vin	Input / Output	$V_{IN}$ Supply Input: Power input / output; bi-directional switch when $V_{IN\_SEL} = HIGH$ .
A2, A3, B3, C3	V <sub>OUT</sub>	Input / Output	Switch Output: Power input / output
C2	EN	Input	<b>Enable</b> : Active HIGH; EN voltage $\ge 2.5$ V can power internal circuit when V <sub>IN</sub> and V <sub>BUS</sub> are absent. 1 M $\Omega$ pull-down resistor is included.
D4	Vin_sel	Input / Output	Supply Selector & Status: Input power source selection input and status output. This signal is ignored during EN=LOW.Selector input during EN=HIGH:HIGH = switch $V_{IN}$ to $V_{OUT} / LOW$ = switch $V_{BUS}$ to $V_{OUT}$ .Status output during EN=LOW:HIGH = $V_{IN}$ is used for $V_{OUT} / LOW$ = $V_{BUS}$ is used for $V_{OUT}$ .
D3	DF_IN	Input	<b>Default Supply Selector during EN=LOW</b> : Floating = V <sub>BUS</sub> connects to V <sub>OUT</sub> . LOW = V <sub>IN</sub> connects to V <sub>OUT</sub> . This signal is ignored during EN=HIGH. 1 $\mu$ A pull-up current source is included.
B2	Other_VIN_AVA	Output	Other Supply Input Status: Open-drain output. HIGH-Z = both $V_{IN}$ and $V_{BUS}$ are valid. LOW = the other power source is not valid.
D1, D2	GND		Ground

Table	e1. T	ruth Table					
EN	$V_{IN} > V_{UVLO}$	V <sub>BUS</sub> >V <sub>UVLO</sub>	$V_{\text{IN}\_\text{SEL}}$	DF_IN	Other_V <sub>IN_AVA</sub>	V <sub>OUT</sub>	Comment
HIGH	х	х	LOW	х	HI-Z if VIN & VBUS > VUVLO LOW if VIN or VBUS < VUVLO	VBUS	Vout is selected by
HIGH	Х	х	HIGH	Х	HI-Z if VIN & VBUS > VUVLO LOW if VIN or VBUS < VUVLO	V <sub>IN</sub>	Bidirectional channel
LOW	YES	NO	HIGH	Х	LOW	VIN	Automatic selection to
LOW	NO	YES	LOW	х	LOW	V <sub>BUS</sub>	valid input V <sub>IN_SEL</sub> is output.
LOW	YES	YES	LOW	Floating	HIGH-Z	V <sub>BUS</sub>	V <sub>OUT</sub> is selected by
LOW	YES	YES	HIGH	LOW	HIGH-Z	V <sub>IN</sub>	DF_IN V <sub>IN_SEL</sub> is output.
LOW	NO	NO	NO	Х	Floating	Floating	OFF

Notes:

Internal pull-down at EN.
1 μA pull-up current source at DF\_IN.

### Absolute Maximum Ratings

Stresses exceeding the Absolute Maximum Ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol		Min.	Max.	Unit			
		-1.4	40.0				
N/	VIN, VBUS to GND	Pulsed, 100 ms Maximum Nor	n-Repetitive	-2.0	18.0	Ň	
Vpin	V <sub>OUT</sub> to GND <sup>(3)</sup>			-0.3	16.0	V	
	EN, DF_IN, VIN_SEL, O	ther_V <sub>IN_AVA</sub> to GND		-0.3	6.0		
			T <sub>A</sub> =25°C		2.70		
	Maximum Cantinuaus	Quitab Qurrant ner Obernel	T <sub>A</sub> =65°C		2.70	A	
Isw	Maximum Continuous	Switch Current per Channel	T <sub>A</sub> =75°C		2.50		
			2.25				
t <sub>PD</sub>	Total Power Dissipation	on at T <sub>A</sub> =25°C		2.25	W		
TJ	Operating Junction Te	mperature	nperature				
T <sub>STG</sub>	Storage Junction Tem	Storage Junction Temperature					
θJA	Thermal Resistance,	lunction-to-Ambient (1in. Square	Pad of 2 oz. Copper)		55(4)	°C/W	
		Human Body Model, ANSI/ESDA/JEDEC JS-001-2012					
		Charged Device Model, JESD	Charged Device Model, JESD22-C101				
ESD	Electrostatic Discharge Capability		Air Discharge (VIN, VBUS to GND)	15.0		kV	
		IEC61000-4-2 System Level <sup>(</sup> 5	Contact Discharge (VIN, VBUS to GND)	8.0			

#### Notes:

- 3. If an external voltage of more than 13 V is applied to  $V_{OUT}$ , the slew rate should be <1 V/ms from 13 V.
- 4. Measured using 2S2P JEDEC standard PCB.
- 5. System-level ESD can be guaranteed by design.

# **Recommended Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. ON Semiconductor does not recommend exceeding them or designing to Absolute Maximum Ratings.

Symbol	Parameters	Min.	Max.	Unit
N/	VIN	4.0	12.4	V
VPIN	V <sub>BUS</sub>	4.0	12.4	v
TA	Ambient Operating Temperature	-40	+85	°C

# **Electrical Characteristics**

VIN=4 to 12.4 V, VBUS=4 to 12.4 V, TA=-40 to 85°C unless otherwise noted. Typical values are at VIN=VBUS=5 V, EN=HIGH and TA=25°C unless otherwise noted.

Symbol	Parameters	Condition	Min.	Тур.	Max.	Uni	
Vin	Input Voltage from V <sub>IN</sub>		4.0		12.4	V	
VBUS	Input Voltage from V <sub>BUS</sub>		4.0		12.4	V	
		I <sub>OUT</sub> =0 mA, EN=HIGH, V <sub>IN</sub> or V <sub>BUS</sub> =5 V		55	120	μA	
lq	Quiescent Current	IOUT=0 mA, EN=5 V, VIN and VBUS=GND		33	70	μA	
		V <sub>IN</sub> =12 V, I <sub>OUT</sub> =200 mA, T <sub>A</sub> =25°C		95		μγγ	
		VIN=8 V, IOUT=200 mA, TA=25°C		95			
	On Resistance for V <sub>IN</sub>	VIN=5 V, IOUT=200 mA, TA=25°C		95	150	mΩ	
		V <sub>IN</sub> =5 V, I <sub>OUT</sub> =200 mA, T <sub>A</sub> =25°C to 85°C <sup>(6)</sup>			200		
Ron		V <sub>BUS</sub> =12 V, I <sub>OUT</sub> =200 mA, T <sub>A</sub> =25°C		70			
		V <sub>BUS</sub> =6 V, I <sub>OUT</sub> =200 mA, T <sub>A</sub> =25°C		70			
	On Resistance for V <sub>BUS</sub>	V <sub>BUS</sub> =5 V, I <sub>OUT</sub> =200 mA, T <sub>A</sub> =25°C		70	100	mΩ	
		V <sub>BUS</sub> =5 V, I <sub>OUT</sub> =200 mA, T <sub>A</sub> =25°C to 85°C <sup>(6)</sup>					
VIH	Input Logic High Voltage	V <sub>IN</sub> , V <sub>BUS</sub> = 4.0 V~12.4 V	1.15			V	
VIL	Input Logic Low Voltage	V <sub>IN</sub> , V <sub>BUS</sub> =4.0 V~12.4 V			0.52	V	
Ven(otg)	EN Voltage in OTG Mode <sup>(6)</sup>	VIN & VBUS=Float or VIN & VBUS <vuvlo< td=""><td>2.5</td><td></td><td></td><td>V</td></vuvlo<>	2.5			V	
$R_{\text{EN}_{PD}}$	Pull-Down Resistance at EN			1000		kΩ	
Protectio	n						
		VIN or VBUS Rising	3.05	3.50	4.00	V	
Vuvlo	Under-Voltage Lockout Threshold	VIN or VBUS Falling	2.55	3.00	3.55	V	
VUVHYS	Under-Voltage Lockout Hysteresis			0.5		V	
		V <sub>IN</sub> Rising Threshold	12.9	14.0	15.0	V	
N/		V <sub>IN</sub> Falling Threshold	12.4	13.5	14.5	V	
Vovlo	Over-Voltage Lockout Threshold	V <sub>BUS</sub> Rising Threshold	12.9	14.0	15.0	V	
		VBUS Falling Threshold	12.4	13.5	14.5	V	
		Vin		0.5		V	
Vovhys	Over-Voltage Lockout Hysteresis	V <sub>BUS</sub>		0.5		V	
T <sub>SDN</sub>	Thermal Shutdown Threshold			150		°C	
TSDNHYS	Thermal Shutdown Hysteresis			20		°C	
Reverse (	Current Blocking (RCB)	•	•	•			
IRCB	VIN or VBUS Current During RCB	Vout=8 V, VIN or VBUS=GND			30	μA	
Dynamic	Characteristics						
<b>t</b> -	Vout Rise Time, VBUS <sup>(6,7)</sup>			90			
t <sub>R</sub>	V <sub>OUT</sub> Rise Time, V <sub>IN</sub> (6,7)			50		μs	
t⊧	VOUT Fall Time <sup>(6,7)</sup>	V <sub>IN</sub> =V <sub>BUS</sub> =5 V, R <sub>L</sub> =150 Ω, C <sub>L</sub> =4.7 μF, T <sub>A</sub> =25°C		1.4		ms	
<b>t</b> TRAN	Transition Delay <sup>(6,7)</sup>	]	50	100		ms	
t <sub>SD</sub>	Selection Delay <sup>(6,7)</sup>			50		μs	

This parameter is guaranteed by characterization and/or design; not production tested. 6.

 $t_{SD}/t_{TRAN}/t_{R}/t_{F}$  are defined in Figure 6. 7.









Figure 11.V<sub>IN</sub> On Resistance (mΩ) vs. Temperature



Figure 13. V<sub>IN</sub> On Resistance (mΩ) vs. Supply Voltage Figure 14. V<sub>BUS</sub> On Resistance (mΩ) vs. Supply Voltage

7.0







6.0

6.5





# **Operation and Application Information**

The FPF3042 is an 18 V, 2.7 A-rated, Dual-Input Single-Output (DISO) N-channel MOSFET load switch with slew-rate-controlled and low on resistance. The input operating range is from 4 V to 12.4 V at V<sub>BUS</sub> and at V<sub>IN</sub>. The internal circuitry is powered from the highest voltage source among V<sub>IN</sub>, V<sub>BUS</sub>, and EN.

#### **Input Power-Source Selection**

The input power source can be selected by V<sub>IN\_SEL</sub> and DF\_IN, respectively, depending on the EN state. When EN is HIGH, the input source is selected by V<sub>IN\_SEL</sub> regardless of DF\_IN. If V<sub>IN\_SEL</sub> is LOW, V<sub>BUS</sub> is selected. If V<sub>IN\_SEL</sub> is HIGH, V<sub>IN</sub> is selected.

Table 2.	Input	Power	Selection	by	VIN	SEL

EN	$V_{IN} > V_{UVLO}$	V <sub>BUS</sub> >V <sub>UVLO</sub>	$V_{\text{IN}\_\text{SEL}}$	DF_IN	V <sub>OUT</sub>
HIGH	Х	Х	LOW	Х	$V_{BUS}$
HIGH	Х	Х	HIGH	Х	VIN

When EN is LOW, the input source is selected by DF\_IN and the number of valid input sources. If only one input source is valid (greater than V<sub>UVLO(MAX)</sub>), the source is selected automatically, regardless of DF\_IN, to make charging path in case the battery is depleted. If both V<sub>BUS</sub> and V<sub>IN</sub> have valid input sources, the input source is selected by DF\_IN. If DF\_IN is LOW, V<sub>IN</sub> is selected. If DF\_IN is HIGH or floating, V<sub>BUS</sub> is selected. DF\_IN is biased HIGH with an internal 1  $\mu$ A pull-up current source.

Table 3. Input Power Selection by DF_I
--

EN	V <sub>IN</sub> >V <sub>UVLO</sub>	V <sub>BUS</sub> >V <sub>UVLO</sub>	$V_{\text{IN}\_\text{SEL}}$	DF_IN	V <sub>OUT</sub>
LOW	YES	NO	HIGH	Х	Vin
LOW	NO	YES	LOW	Х	VBUS
LOW	YES	YES	LOW	Floating	VBUS
LOW	YES	YES	HIGH	LOW	Vin
LOW	NO	NO	Х	Х	Floating

 $V_{IN\_SEL}$  can be the status output to indicate which input power source is used during EN is LOW. If  $V_{IN}$  is used,  $V_{IN\_SEL}$  shows HIGH. If  $V_{BUS}$  is used,  $V_{IN\_SEL}$  shows LOW. The voltage level of HIGH signal is 5.3 V if any one of  $V_{IN}$ ,  $V_{BUS}$ , or EN is higher than 5.3 V. The signal

is highest voltage among  $V_{\text{IN}},\,V_{\text{BUS}},$  and EN if none of them is higher than 5.3 V.

#### EN Voltage for Control Logic Power Supply

Internal control logic is powered from the highest voltage among V<sub>IN</sub>, V<sub>BUS</sub>, and V<sub>EN</sub>. If valid V<sub>IN</sub> or V<sub>BUS</sub> higher than UVLO is applied, ON/OFF control by EN should be accomplished with V<sub>IH</sub>/V<sub>IL</sub>. If EN powers the internal control block without valid V<sub>IN</sub> and V<sub>BUS</sub>, more than 2.5 V is required on the EN pin to operate properly.

#### **Over-Voltage Protection (OVP)**

The FPF3042 includes over-voltage protection at both V<sub>IN</sub> and V<sub>BUS</sub>. If V<sub>IN</sub> or V<sub>BUS</sub> is higher than 14 V (typical), the power switch is off until input voltage is lower than the over-voltage trip level by a hysteresis voltage of 0.5 V.

#### **Reverse Power Supply for OTG**

The bidirectional switch allows reverse power for On-The-Go (OTG) operation. Even if both  $V_{IN}$  and  $V_{BUS}$  are unavailable, reverse power can be supported if internal control circuitry is powered by EN.

#### **Reverse-Current Blocking (RCB)**

FPF3042 supports reverse-current blocking during EN LOW and an unselected channel.

#### **Thermal Shutdown**

During thermal shutdown, the power switch is turned off if junction temperature exceeds 150°C to avoid damage.

#### Wireless Charging System

FPF3042 can be used as an input power selector supporting Travel Adaptor (TA) and Wireless Charging (WC) with a single-input-based battery charger or Power Management IC (PMIC), including a charging block as shown in Figure 31. The system can recognize an input power source change between 5 V TA and 5 V WC without detection circuitry because FPF3042 has a 100 ms transition delay. OTG Mode can be supported without an additional power path, such as a MOSFET.



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D	E	X	Y
96 mm ±0.03 mm	1.76 mm ±0.03 mm	0.28 mm	0.38 mm







# RECOMMENDED LAND PATTERN (NSMD PAD TYPE)



TOP VIEW



SIDE VIEWS

NOTES:

- A. NO JEDEC REGISTRATION APPLIES.
- B. DIMENSIONS ARE IN MILLIMETERS.
- C. DIMENSIONS AND TOLERANCE PER ASME Y14.5M, 1994.
- D. DATUM C IS DEFINED BY THE SPHERICAL CROWNS OF THE BALLS.

<u>E</u>PACKAGE NOMINAL HEIGHT IS 586 MICRONS ±39 MICRONS (547-625 MICRONS).

F. FOR DIMENSIONS D, E, X, AND Y SEE PRODUCT DATASHEET.

G. DRAWING FILNAME: MKT-UC016AArev2.

APPROVALS	DATE	FAIR	<u>ен</u> ш				
L. England	10-26-09	SEMICO					
<sup>DFTG. CHK.</sup> E. Shacham	10-26-09	10					
ENGR. CHK.		16BALL WLCSP, 4X4 ARRAY 0.4MM PITCH, 250UM BALL					
			.4101101	F I I G I , 2			
PROJECTIO	N	SCALE	SIZE	DRAWING NUMBER	2	REV	
		N/A	N/A	MKT-l	JC016AA	2	
INCH IMM		DO NO	<b>ESCALE</b>	DRAWING	SHEET 1 of	1	



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